LED and Photosensor Pairs OPS666, OPS667, OPS691, OPS692, OPS693, OPS693 Peatures: High current transfer ratio Low-cost plastic package Dextage (OPS691, OPS692, OPS693 and OPS698)

Description:

Each LED/Photosensor pair in the series consists of a gallium arsenide infrared emitting diode and a NPN silicon phototransistor, mounted in a T-1 package (OPS666, OPS667) or in a matched lateral side-looking plastic package (OPS691, OPS692, OPS693 and OPS698).

Matched pairs are desirable where the application is unique and the quantity required does not justify assembly tooling costs. If separation between the LED and sensor is greater than two times the specified $IC_{(ON)}$ distance, proper alignment becomes critical. Although sold as pairs, emitters and sensors are packaged separately for handling ease.

Please note that the sensor is sensitive to ambient light.

Applications:

- Non-contact reflective object sensor
- Assembly line automation
- Machine automation
- Machine safety
- End of travel sensor
- Door sensor

Ordering Information				
Part Number	Output	Package Style	Description	Lead Length
OPS666	Transistor	T-1	Gallium arsenide infrared emitting diode (OP165) NPN silicon phototransistor (OP505)	0.50" (`1.700 mm)
OPS667	Transistor	T-1	Gallium arsenide infrared emitting diode (OP165) NPN silicon phototransistor (OP505)	0.50" (`1.700 mm)
OPS691	Transistor	Lateral Side-looking	Gallium arsenide infrared emitting diode (OP140) NPN silicon phototransistor (OP550)	0.50" (`1.700 mm)
OPS692	Transistor	Lateral Side-looking	Gallium arsenide infrared emitting diode (OP140) NPN silicon phototransistor (OP550)	0.50" (`1.700 mm)
OPS693	Transistor	Lateral Side-looking	Gallium arsenide infrared emitting diode (OP140) NPN silicon phototransistor (OP550)	0.50" (`1.700 mm)
OPS698	Transistor	Lateral Side-looking	Gallium arsenide infrared emitting diode (OP145) NPN silicon phototransistor (OP555)	0.50" (`1.700 mm)



General Note

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OPS666, OPS667, OPS691, OPS692, OPS693, OPS698

Electrical Specifications

OPS666, OPS667





DIMENSIONS ARE IN INCHES AND [MILLIMETERS].

Pin #	LED & Diode X=0.060" (1.5	Transistor X=0" (0.0 mm)		
1	Anode	Emitter		
2	Cathode	Collector		

OPS691, OPS692, OPS693



DIMENSIONS ARE IN INCHES AND [MILLIMETERS].

Pin #	LED X=0.060" (1.5	Sensor X=0" (0.0 mm)		
1	Cathode	Emitter/Anode		
2	Anode	Collector/Cathode		

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OPS666, OPS667, OPS691, OPS692, OPS693, OPS698

Electrical Specifications

OPS698



DIMENSIONS ARE IN INCHES AND [MILLIMETERS].

Pin #	Diode		
1	Cathode		
2	Anode		

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OPS666, OPS667, OPS691, OPS692, OPS693, OPS698

Electrical Specifications

Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

Storage & Operating Temperature Range	-40° C to +100° C	
Lead Soldering Temperature [1/16 inch (1.6mm) from the case for 5 sec. with soldering iron]	260° C ⁽¹⁾	
Input Diode		
Forward DC Current	50 mA	
Peak Forward Current (1 μs pulse width, 300 pps)	3.0 A	
Reverse DC Voltage	2.0 V	
Power Dissipation	100 mW ⁽²⁾	
Output Photosensor (OPS666/667) or Output Phototransistor (691/692/693/698)		
Collector-Emitter Voltage	30 V	
Emitter-Collector Voltage	5 V	
Power Dissipation	100 mW ⁽²⁾	

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OPS666, OPS667, OPS691, OPS692, OPS693, OPS698



Electrical Specifications

Electrical Characteristics (T_A = 25° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	ТҮР	ΜΑΧ	UNITS	TEST CONDITIONS
Input Diode						
V _F	Forward Voltage	-	-	1.6	V	I _F = 20 mA
I _R	Reverse Current	-	-	100	μA	$V_R = 2 V$
Output Phototransistor						
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	30	-	-	V	$I_{C} = 100 \ \mu A, \ E_{E} = 0$
V _{(BR)ECO}	Emitter-Collector Breakdown Voltage	5.0	-	-	V	I _E = 100 μA, E _E = 0
I _{CEO}	Collector-Emitter Dark Current OPS666/667 OPS691/692/693 OPS698	- -	- -	100 100 100	nA nA nA	$V_{CE} = 15 \text{ V}, \text{ I}_{F} = 0, \text{ I}_{E} = 0$ $V_{CE} = 10 \text{ V}, \text{ I}_{F} = 0, \text{ I}_{E} = 0$ $V_{CE} = 10 \text{ V}, \text{ I}_{F} = 0, \text{ I}_{E} = 0$
Combined						
V _{CE(SAT)}	Collector-Emitter Saturation Voltage OPS666/667 OPS691/692/693 OPB698	- -	- -	- 0.4 0.4	- V V	- I _F = 20 mA, I _C = 50 μA ⁽³⁾ I _F = 20 mA, I _C = 50 μA ⁽³⁾
I _{C(ON)}	On-State Collector Current OPS666 OPS667 OPS691 OPS692 OPS693, OPS698	1.0 5.0 500 1.0 2.0	- - -		mA mA μA mA mA	V _{CE} = 5 V, I _F = 20 mA ⁽³⁾ V _{CE} = 10 V, I _F = 20 mA ⁽³⁾

Notes:

(1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.

(2) Derate linearly 1.33 mW/° C above 25° C.

(3) Distance from lens tip to lens tip is 0.250" (6.35 mm) - OPS666, OPS667

Distance from lens tip to lens tip is 0.125" (3.175 mm) - OPS691 thru OPS698

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OPS666, OPS667, OPS691, OPS692, OPS693, OPS698



Performance

OPS666, OPS667



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OPS666, OPS667, OPS691, OPS692, OPS693, OPS698



OPS691, OPS692, OPS693 Forward Current vs Dark Current vs **Coupling Characteristics** Free Air Temperature **Forward Voltage** of OP140 and OP550 10 K 50 1.0 Test Condition V_{CE} = 15 V E. = 0 1K ICEO – DARK CURRENT – nA IF – FORWARD CURRENT – mA 40 0.8 RELATIVE OUTPUT CURRENT 100 TA = 70°C 30 10 0.6 TA = 25 1 20 0.4 -40 0.1 TΔ 10 0.2 0.01 0.001 0 ٥ 60 80 100 -20 0 20 40 -40 0.8 1.0 1.2 1.4 1.6 0 0.4 0.6 0,8 1.0 0.2 0 TA - AMBIENT TEMPERATURE - °C VF - FORWARD VOLTAGE - V DISTANCE BETWEEN LENS TIPS - Inches **Relative Power Output vs** Normalized Collector Current vs **Relative Output Current vs** Forward Current (LED) Angular Displacement Free Air Temperature 250 1.0 1.2 IC NORMALIZED COLLECTOR CURRENT ¥ 200 1.0 0.8 RELATIVE OUTPUT CURRENT RELATIVE POWER OUTPUT 0.8 150 0.6 0.6 0.5 100 0.4 Test Condi ns: λ = 895 nm 0.4 IF = 100 mA VCE = 5 V 50 Test Co 0,2 ons VCE = 5 V 0.2 Lens to Lens Distance is 6 inches (152.4 m IF = 10 mA 0 0 0 50 30 40 10 20 0 45 -45 -25 -505 25 -50 -25 0 25 50 75 100 IF - FORWARD CURRENT - mA θ - ANGULAR DISPLACEMENT - Degrees TA - AMBIENT TEMPERATURE - °C

Performance

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 θ - ANGULAR DISPLACEMENT - Degrees

Performance

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IF - FORWARD CURRENT - mA

TA - AMBIENT TEMPERATURE - °C

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